
HD74AC139/HD74ACT139

Dual 1-of-4 Decoder/Demultiplexer

HITACHI

Description

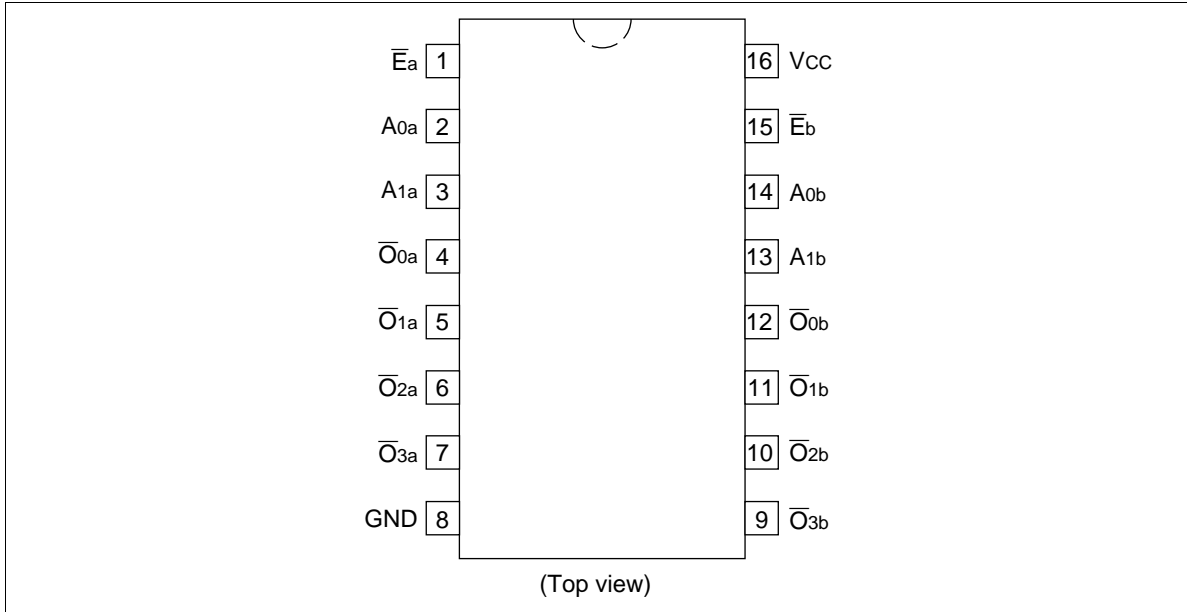
The HD74AC139/HD74ACT139 is a high-speed, dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each accepting two inputs and providing four mutually-exclusive active-Low outputs. Each decoder has an active-Low Enable input which can be used as a data input for a 4-output demultiplexer. Each half of the HD74AC139/HD74ACT139 can be used as a function generator providing all four minterms of two variables.

Features

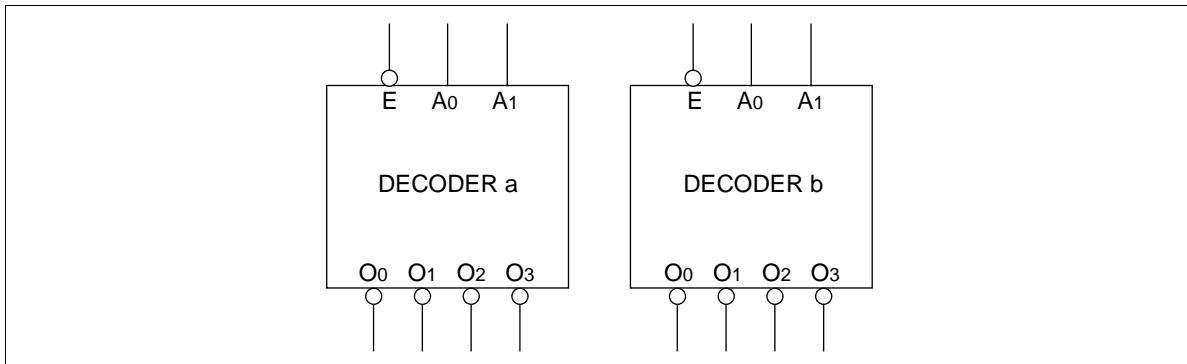
- Multifunction Capability
- Two Completely Independent 1-of-4 Decoders
- Active Low Mutually Exclusive Outputs
- Outputs Source/Sink 24 mA
- HD74ACT139 has TTL-Compatible Inputs

HD74AC139/HD74ACT139

Pin Arrangement



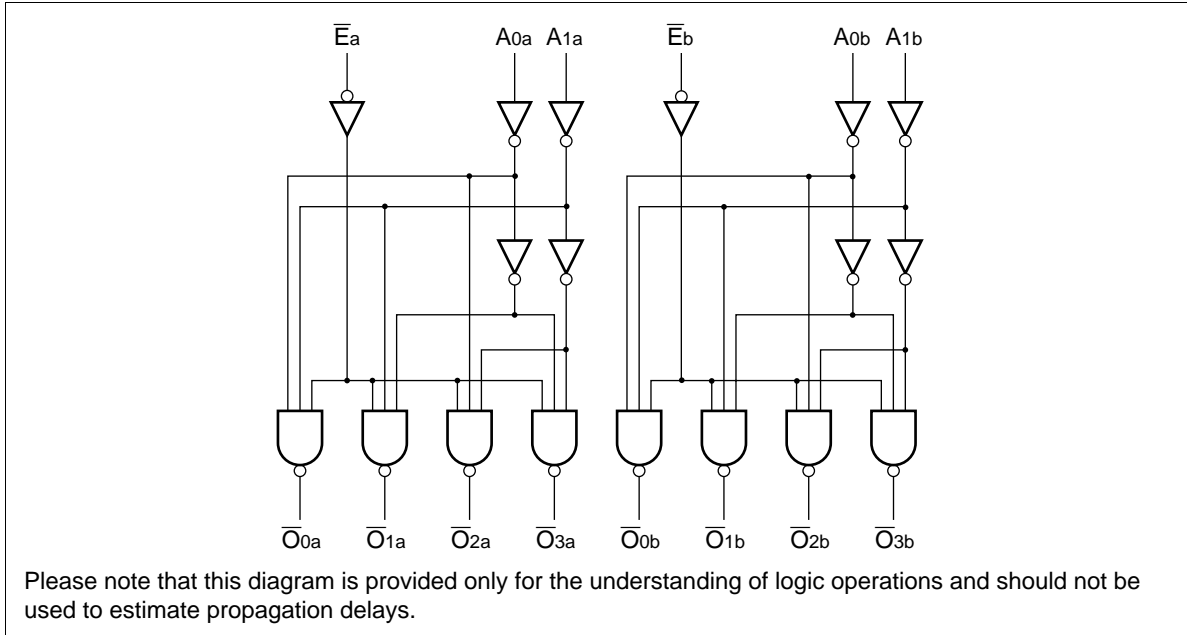
Logic Symbol



Pin Names

- A₀, A₁ Address Inputs
- \bar{E} Enable Inputs
- \bar{O}_0 to \bar{O}_3 Outputs

Logic Diagram



Functional Description

The HD74AC139/HD74ACT139 is a high-speed dual 1-of-4 decoder/demultiplexer. The device has two independent decoders, each of which accepts two binary weighted inputs (A_0 to A_1) and provides four mutually exclusive active-Low outputs (\bar{O}_0 to \bar{O}_3). Each decoder has an active-Low enable (\bar{E}). When \bar{E} is High all outputs are forced High. The enable can be used as the data input for a 4-output demultiplexer application. Each half of the HD74AC139/HD74ACT139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in Figure a, and thereby reducing the number of packages required in a logic network.

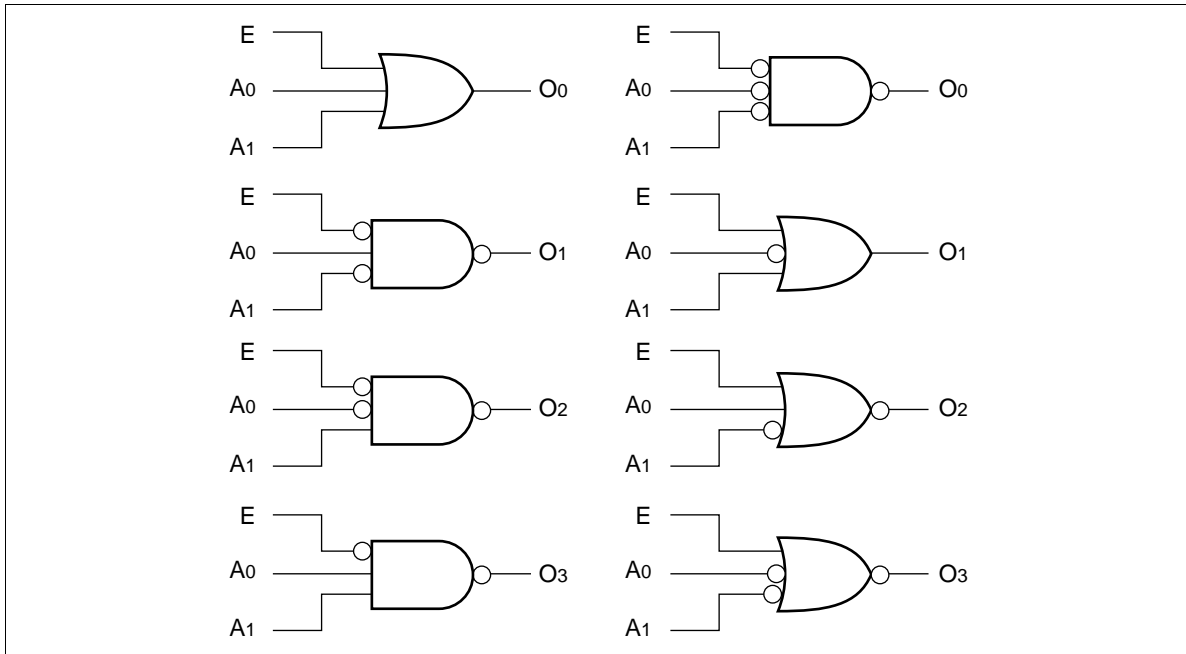
Truth Table

Inputs			Outputs			
\bar{E}	A_0	A_1	\bar{O}_0	\bar{O}_1	\bar{O}_2	\bar{O}_3
H	X	X	H	H	H	H
L	L	L	L	H	H	H
L	H	L	H	L	H	H
L	L	H	H	H	L	H
L	H	H	H	H	H	L

H : High Voltage Level
 L : Low Voltage Level
 X : Immaterial

HD74AC139/HD74ACT139

Figure a: Gate Functions (each half)



DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I_{CC}	80	μA	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, $T_a = \text{Worst case}$
Maximum quiescent supply current	I_{CC}	8.0	μA	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, $T_a = 25^\circ\text{C}$
Maximum I_{CC}/input (HD74ACT139)	I_{CCT}	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}$, $V_{CC} = 5.5 \text{ V}$ $T_a = \text{Worst case}$

HD74AC139/HD74ACT139

AC Characteristics: HD74AC139

Item	Symbol	V _{CC} (V)* ¹	Ta = +25°C C _L = 50 pF			Ta = -40°C to +85°C C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
Propagation delay A _n to \overline{O}_n	t _{PLH}	3.3	1.0	8.0	11.5	1.0	13.0	ns
		5.0	1.0	6.5	8.5	1.0	9.5	
Propagation delay A _n to \overline{O}_n	t _{PHL}	3.3	1.0	7.0	10.0	1.0	11.0	ns
		5.0	1.0	5.5	7.5	1.0	8.5	
Propagation delay \overline{E}_n to \overline{O}_n	t _{PLH}	3.3	1.0	9.5	12.0	1.0	13.0	ns
		5.0	1.0	7.0	8.5	1.0	10.0	
Propagation delay \overline{E}_n to \overline{O}_n	t _{PHL}	3.3	1.0	8.0	10.0	1.0	11.0	ns
		5.0	1.0	6.0	7.5	1.0	8.5	

Note: 1. Voltage Range 3.3 is 3.3 V ± 0.3 V
Voltage Range 5.0 is 5.0 V ± 0.5 V

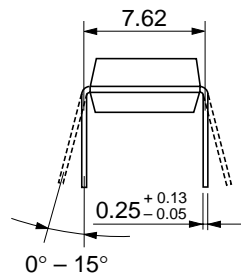
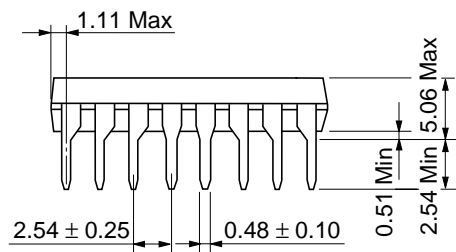
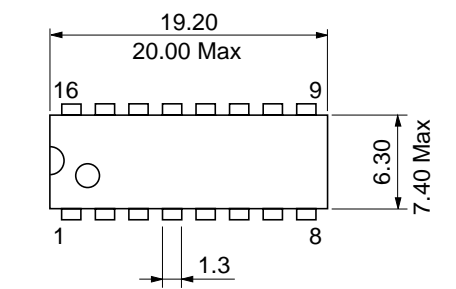
AC Characteristics: HD74ACT139

Item	Symbol	V _{CC} (V)* ¹	Ta = +25°C C _L = 50 pF			Ta = -40°C to +85°C C _L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
Propagation delay A _n to \overline{O}_n	t _{PLH}	5.0	1.0	6.0	8.5	1.0	9.5	ns
Propagation delay A _n to \overline{O}_n	t _{PHL}	5.0	1.0	6.0	9.5	1.0	10.5	ns
Propagation delay \overline{E}_n to \overline{O}_n	t _{PLH}	5.0	1.0	7.0	10.0	1.0	11.0	ns
Propagation delay \overline{E}_n to \overline{O}_n	t _{PHL}	5.0	1.0	7.0	9.5	1.0	10.5	ns

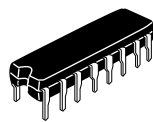
Note: 1. Voltage Range 5.0 is 5.0 V ± 0.5 V

Capacitance

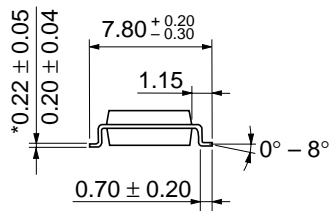
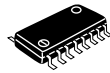
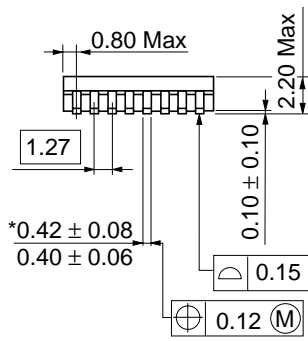
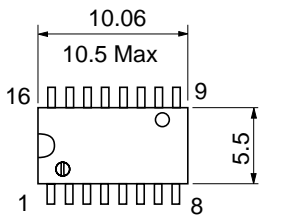
Item	Symbol	Typ	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Power dissipation capacitance	C _{PD}	40.0	pF	V _{CC} = 5.0 V



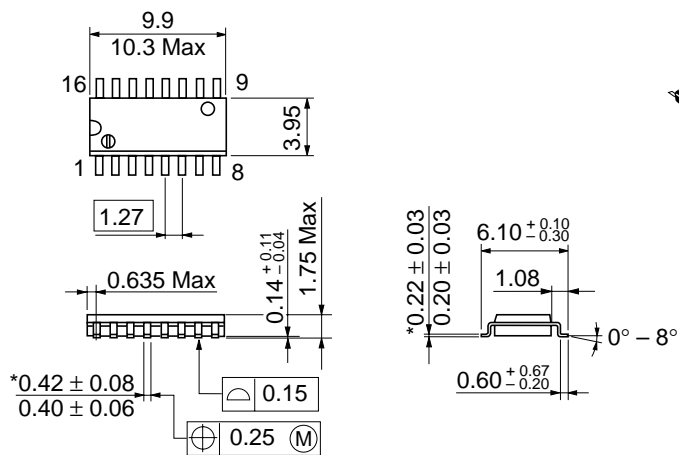
Unit: mm



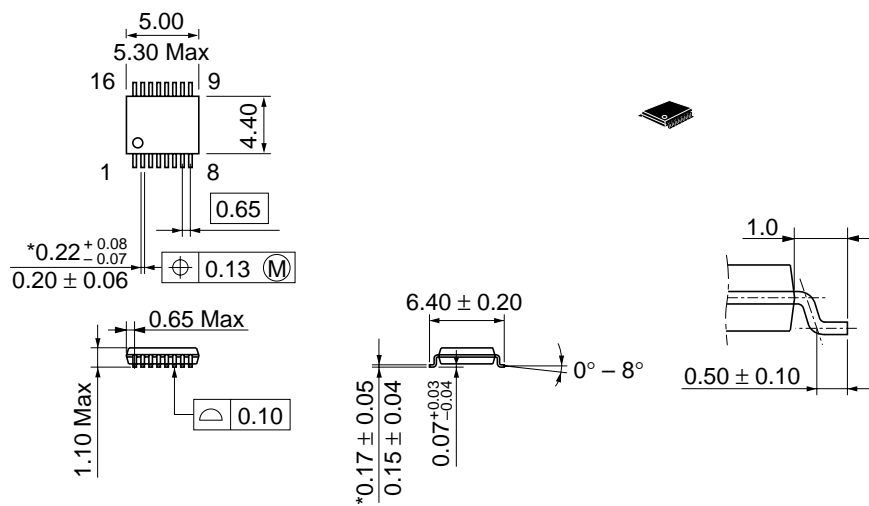
Unit: mm



Unit: mm



Unit: mm



Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
 Asia (Singapore) : <http://www.has.hitachi.com.sg/grp3/sicd/index.htm>
 Asia (Taiwan) : http://www.hitachi.com.tw/E/Product/SICD_Frame.htm
 Asia (HongKong) : <http://www.hitachi.com.hk/eng/bo/grp3/index.htm>
 Japan : <http://www.hitachi.co.jp/Sicd/indx.htm>

For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic components Group
Domacher StraÙe 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 049318
Tel: 535-2100
Fax: 535-1533

Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building, No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX